ASSP for Mobile Telephone

VCO (700 to 2000 MHz)

VC-80 Series

DESCRIPTION

With excellent C/N characteristics and low current consumption, this VCO series is ideal for PDC, PHS, CDMA, PCS and GSM mobile communication equipment. The VC-80 series can be used in any frequency band in the 700MHz to 2000MHz range. The device utilizes FUJITSU MEDIA DEVICE's high-frequency design technology, high-density mounting technology, and frequency adjustment technology to provide a high level of reliability in addition to high performance and small size.

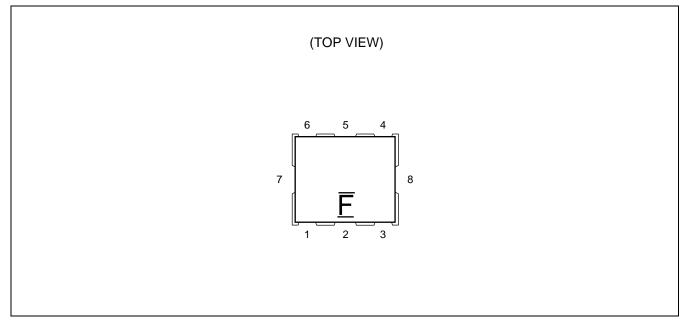
FEATURES

- Superior noise characteristics (C/N, S/N)
- · High level of stability in response to ambient temperature and load variations
- FUJITSU MEDIA DEVICE's proprietary fabrication process provides the uniformity of the central frequency distribution
- Small size, light-weight, slim-package : 5.5 × 4.8 × 1.6 mm (Typ.)
- SMD-type taping specifications suitable for automatic mounting and reflow soldering

PACKAGE



■ PIN ASSIGNMENT



■ PIN DESCRIPTION

Pin No.	Symbol	Description
1	Vt	Control voltage
2	GND	GND
3	Vcc	Power supply voltage
4	OUT	Output
5	GND	GND
6	GND	GND
7	GND	GND
8	GND	GND

■ PRODUCT LINEUP (STANDARD MODELS)

System	Center Frequency (MHz)	Band Width (MHz)	Power Supply Voltage (V)	Part Number
PDC800 makitori	717	±37.5	2.2 ± 0.2	VC-2R2A80-0717K
cdmaOne	739	±19.5	2.8 ± 0.1	VC-2R8A80-0739A
PHS Data communication device	1668	±18.3	3.0 ± 0.2	VC-3R0A80-1668N
K-PCS	1635	±15	2.8 ± 0.15	VC-2R8A80-1635L
CDMA	967	±13	2.8 ± 0.15	VC-2R8A80-0967L

ELECTRICAL CHARACTERISTICS

1. For PDC800 makitori (Part number : VC-2R2A80-0717K)

Absolute Maximum Ratings

Parameter	Symbol	Ra	Unit		
Farameter	Symbol	Min.	Max.	– Unit	
Input DC voltage	Vcc		+ 3.0	V	
Control voltage	Vt	—	+ 3.0	V	
Operating temperature	Та	-20	+70	°C	
Storage temperature	Tstg	-30	+80	°C	
Storage humidity	Hstg	5	95	%	

WARNING: VCO can be permanently damaged by application of stress (voltage, temperature, humidity, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

• Electrical Characteristics

(Ta = +25 °C ± 3 °C)

Parameter	Cumhal	Conditions		Value		Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	
Current consumption	lcc	Vcc = 2.2 V, Vt = 1.4 V			6.8*	mA
Frequency	fmin	$V_{CC} = 2.2 V, Vt = 0.4 V$			680.0*	MHz
Frequency	fmax	Vcc = 2.2 V, Vt = 2.4 V	755.0*		_	MHz
Control voltage sensitivity	kv	(fmax – fmin) / 2.0	44.0		56.0	MHz/V
Oscillator output	Po	Vcc = 2.2 V, Vt = 1.4 V	-7.0*		-1.0*	dBm
C/N	C/N	V _{cc} = 2.2 V, Vt = 1.4 V, Offset = 50 kHz, BW = 21 kHz	67.0* 69.0			dBc/Hz
S/N	S/N	$V_{CC} = 2.2 V, Vt = 1.4 V,$ Dev = ±2 kHz, B.W. = 0.3 kHz to 3 kHz	28.0*			dBc/Hz
Higher harmonics	Hs	$V_{CC} = 2.2 V, Vt = 1.4 V,$ Up to 3rd			-10.0*	dBc
Power supply variation	Push	$V_{CC} = 2.2 V \pm 0.2 V,$ Vt = 1.4 V	_	_	±600*	kHz
Load variation	Pull	Vcc = 2.2 V, Vt = 1.4 V, VSWR = 2 ALL PHASE			±500*	kHz
Temperature drift	Td	Ta = +25 °C ± 45 °C	—	—	±3000*	kHz

* : Ta = $-20 \circ C$ to $+70 \circ C$

2. For cdmaOne (Part number : VC-2R8A80-0739A)

• Absolute Maximum Ratings

Parameter	Symbol	Ra	Rating		
Parameter	Symbol	Min.	Max.	Unit	
Input DC voltage	Vcc		+ 3.2	V	
Control voltage	Vt		+ 3.2	V	
Operating temperature	Та	-30	+80	°C	
Storage temperature	Tstg	-40	+85	°C	
Storage humidity	Hstg	5	95	%	

WARNING: VCO can be permanently damaged by application of stress (voltage, temperature, humidity, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

• Electrical Characteristics

(Ta = +25 °C ± 3 °C)

Parameter	Symbol	Conditions		Value		Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Current consumption	Icc	Vcc = 2.8 V, Vt = 1.5 V	_	_	6.5*	mA
Frequency	fmin	Vcc = 2.8 V, Vt = 0.5 V			719.65*	MHz
Frequency	fmax	Vcc = 2.8 V, Vt = 2.5 V	758.65*	_	—	MHz
Control voltage sensitivity	kv	(fmax – fmin) / 2.0	25.0	31.0	37.0	MHz/V
Oscillator output	Po	Vcc = 2.8 V, Vt = 1.5 V	-4.0*	_	2.0*	dBm
	C/N	Vcc = 2.8 V, Vt = 1.5 V, Offset = 25 kHz, BW = 1 Hz	108.0*			dBc/Hz
		Vcc = 2.8 V, Vt = 1.5 V, Offset = 50 kHz, BW = 1 Hz	113.0*			dBc/Hz
C/N		Vcc = 2.8 V, Vt = 1.5 V, Offset = 100 kHz, BW = 1 Hz	118.0*			dBc/Hz
		Vcc = 2.8 V, Vt = 1.5 V, Offset = 285 kHz, BW = 1 Hz	128.0*	_		dBc/Hz
		Vcc = 2.8 V, Vt = 1.5 V, Offset = 900 kHz, BW = 1 Hz	138.0*	—	_	dBc/Hz
Higher harmonics	Hs	$V_{CC} = 2.8 V, Vt = 1.5 V,$ Up to 3rd			-10.0	dBc
Power supply variation	Push	$V_{CC} = 2.8 V \pm 0.1 V,$ Vt = 1.5 V			±500	kHz
Load variation	Pull	Vcc = 2.8 V, Vt = 1.5 V, VSWR = 2 ALL PHASE			±500	kHz
Temperature drift	Td	Ta = +25 °C ± 55 °C			±3000*	kHz

* : Ta = $-30 \ ^{\circ}C$ to $+80 \ ^{\circ}C$

3. For PHS (Part number : VC-3R0A80-1668N)

Absolute Maximum Ratings

Parameter	Symbol	Ra	Unit	
Parameter	Symbol	Min.	Max.	Unit
Input DC voltage	Vcc	—	+ 3.2	V
Control voltage	Vt	—	+ 3.0	V
Operating temperature	Та	-20	+70	°C
Storage temperature	Tstg	-30	+85	°C
Storage humidity	Hstg	5	95	%

WARNING: VCO can be permanently damaged by application of stress (voltage, temperature, humidity, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

• Electrical Characteristics

 $(Ta = +25 \ ^{\circ}C \pm 3 \ ^{\circ}C)$ Value Symbol Conditions Parameter Unit Min. Max. Тур. Current Vcc = 3.0 V, Vt = 1.25 V lcc ____ 10.0* mΑ consumption Frequency fmin $V_{cc} = 3.0 V, Vt = 0.6 V$ ____ 1649.7* MHz ____ Frequency fmax $V_{CC} = 3.0 V, V_{t} = 1.9 V$ MHz 1686.3 Control voltage (fmax - fmin) / 1.3 kv 43.0 57.0 MHz/V ____ sensitivity Oscillator output Po $V_{CC} = 3.0 V, Vt = 1.25 V$ -6.0* ____ ____ dBm $V_{CC} = 3.0 V, Vt = 1.25 V,$ C/N C/N 110.0* dBc/Hz Offset = 100 kHz, BW = 1 Hz $V_{cc} = 3.0 V, Vt = 1.25 V,$ Higher harmonics Hs -15.0 dBc ____ ____ Up to 3rd Power supply $V_{\rm CC} = 3.0 \ V \pm 0.2 \ V,$ Push ±800 kHz variation Vt = 1.25 V $V_{CC} = 3.0 V, Vt = 1.25 V,$ Pull Load variation ±1000 kHz VSWR = 2 ALL PHASE Temperature drift Τd $Ta = +25 \circ C \pm 45 \circ C$ ±4000* kHz

* : Ta = −20 °C to +70 °C

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4. For K-PCS (Part number : VC-2R8A80-1635L)

Absolute Maximum Ratings

Deremeter	Symbol	Ra	Rating		
Parameter	Symbol	Min.	Max.	Unit	
Input DC voltage	Vcc		+ 7.0	V	
Control voltage	Vt		+ 10.0	V	
Operating temperature	Та	-30	+80	°C	
Storage temperature	Tstg	-40	+85	°C	
Storage humidity	Hstg	5	95	%	

WARNING: VCO can be permanently damaged by application of stress (voltage, temperature, humidity, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

• Electrical Characteristics

(Ta = +25 °C ± 3 °C)

Parameter	Symbol	Conditions		Value		Unit
Farameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Current consumption	Icc	Vcc = 2.8 V, Vt = 1.5 V			8.5	mA
Frequency	fmin	$V_{CC} = 2.8 V, Vt = 0.5 V$			1620.0*	MHz
Frequency	fmax	Vcc = 2.8 V, Vt = 2.5 V	1650.0*	_	—	MHz
Control voltage sensitivity	kv	(fmax – fmin) / 2.0	22.0			MHz/V
Oscillator output	Po	Vcc = 2.8 V, Vt = 1.5 V	-3.0		1.0	dBm
	C/N	V _{cc} = 2.8 V, Vt = 1.5 V, Offset = 1 kHz, BW = 1 Hz	70.0*			dBc/Hz
C/N		Vcc = 2.8 V, Vt = 1.5 V, Offset = 100 kHz, BW = 1 Hz	111.0*			dBc/Hz
		V _{cc} = 2.8 V, Vt = 1.5 V, Offset = 1250 kHz, BW = 1 Hz	134.0*			dBc/Hz
Higher harmonics	Hs	$V_{cc} = 2.8 V, Vt = 1.5 V,$ Up to 3rd			-10.0*	dBc
Spurious	Sp	Vcc = 2.8 V, Vt = 1.5 V	—	_	-70.0*	dBc
Power supply variation	Push	$V_{CC} = 2.8 V \pm 0.15 V,$ Vt = 1.5 V			±700	kHz
Load variation	Pull	Vcc = 2.8 V, Vt = 1.5 V, VSWR = 2 ALL PHASE			±800	kHz
Temperature drift	Td	Ta = +25 °C ± 55 °C			±3000*	kHz

* : Ta = $-30 \circ C$ to $+80 \circ C$

5. For CDMA (Part number : VC-2R8A80-0967L)

• Absolute Maximum Ratings

Parameter	Symbol	Ra	Unit	
Parameter	Symbol	Min.	Max.	Unit
Input DC voltage	Vcc	—	+ 7.0	V
Control voltage	Vt	—	+ 10.0	V
Operating temperature	Та	-30	+80	°C
Storage temperature	Tstg	-40	+85	°C
Storage humidity	Hstg	5	95	%

WARNING: VCO can be permanently damaged by application of stress (voltage, temperature, humidity, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

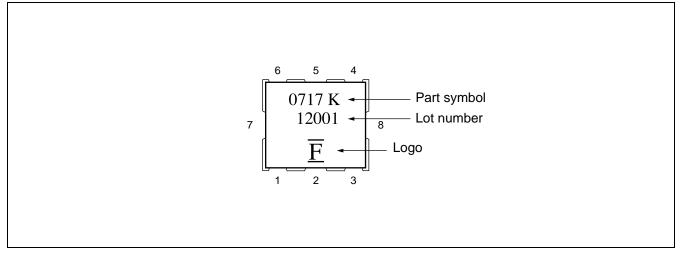
• Electrical Characteristics

(Ta = +25 °C ± 3 °C)

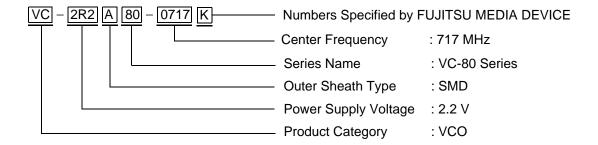
Parameter	Symbol	Conditions		Value		L In it
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Current consumption	Icc	Vcc = 2.8 V, Vt = 1.5 V	_		7.5*	mA
Frequency	fmin	Vcc = 2.8 V, Vt = 0.5 V			954.0*	MHz
Frequency	fmax	Vcc = 2.8 V, Vt = 2.5 V	980*		_	MHz
Control voltage sensitivity	kv	(fmax – fmin) / 2.0	18.0		28.0	MHz/V
Oscillator output	Po	Vcc = 2.8 V, Vt = 1.5 V	-3.0		1.0	dBm
	C/N	Vcc = 2.8 V, Vt = 1.5 V, Offset = 1 kHz, BW = 1 Hz	70.0*		_	dBc/Hz
		Vcc = 2.8 V, Vt = 1.5 V, Offset = 10 kHz, BW = 1 Hz	100.0*		_	dBc/Hz
C/N		Vcc = 2.8 V, Vt = 1.5 V, Offset = 30 kHz, BW = 1 Hz	110.0*		_	dBc/Hz
		Vcc = 2.8 V, Vt = 1.5 V, Offset = 60 kHz, BW = 1 Hz	115.0*		_	dBc/Hz
Higher harmonics	Hs	$V_{CC} = 2.8 V, Vt = 1.5 V,$ Up to 3rd			-10.0*	dBc
Spurious	Sp	Vcc = 2.8 V, Vt = 1.5 V			-70.0*	dBc
Power supply variation	Push	$V_{CC} = 2.8 V \pm 0.15 V,$ Vt = 1.5 V			±500	kHz
Load variation	Pull	Vcc = 2.8 V, Vt = 1.5 V, VSWR = 2 ALL PHASE			±600	kHz
Temperature drift	Td	Ta = +25 °C ± 55 °C	—		±3000*	kHz

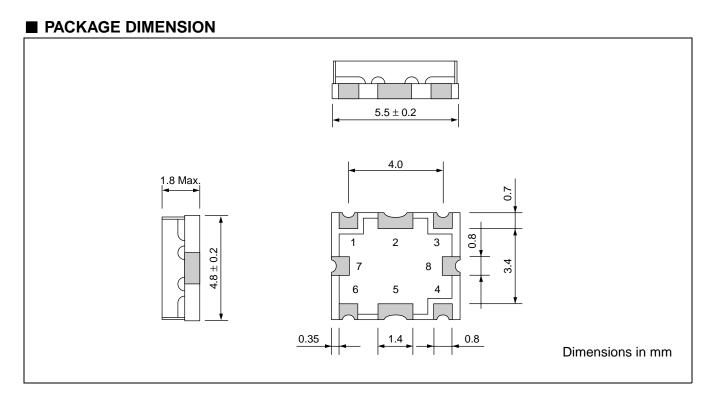
* : Ta = $-30 \ ^{\circ}C$ to $+80 \ ^{\circ}C$

■ MARKING

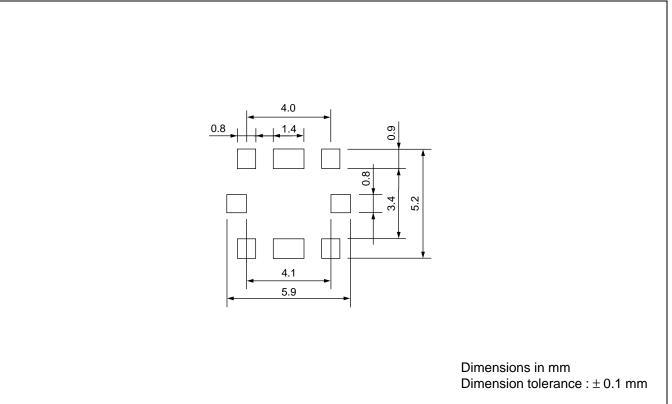


PART NUMBER DESIGNATION



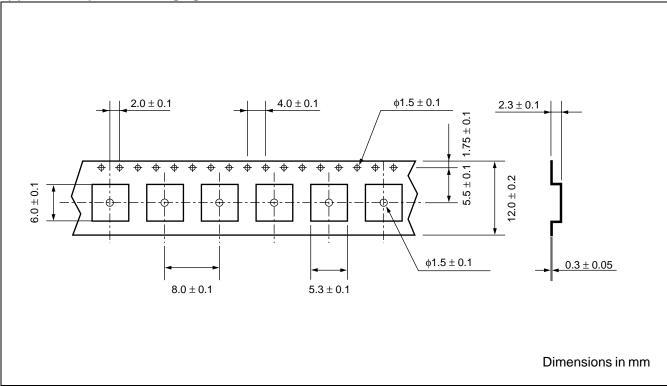


■ RECOMMENDED PATTERN FOR SOLDERING

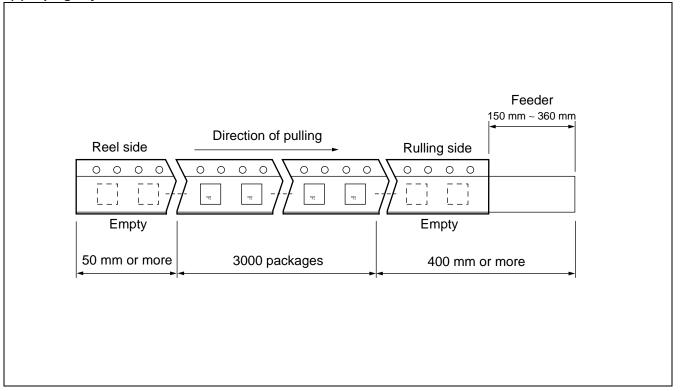


■ TAPING AND PACKAGING

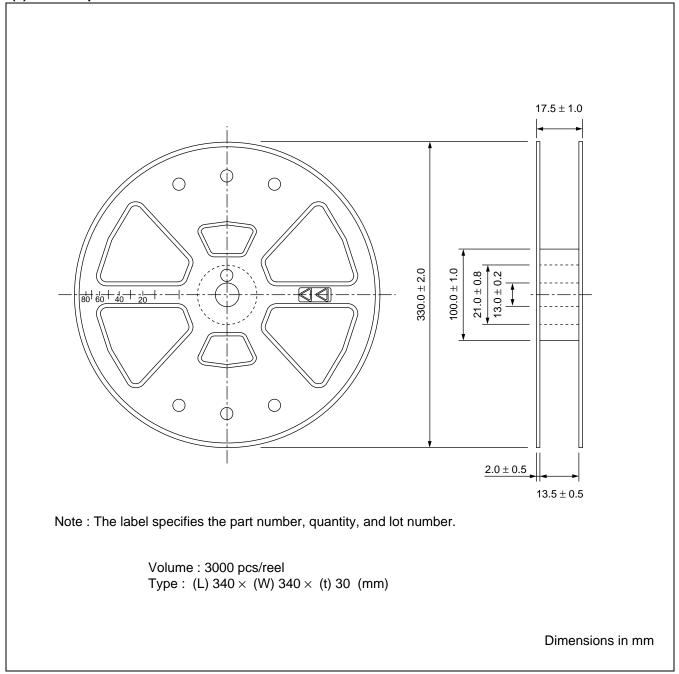
(1) Carrier Tape and Packaging



(2) Taping Layout

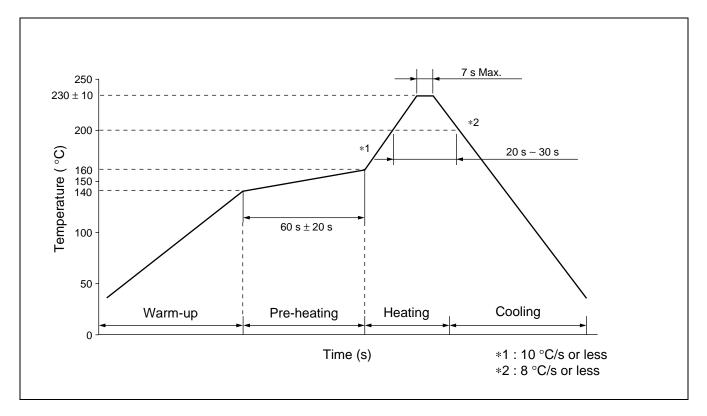


(3) Reel Shape and Dimensions



■ REFLOW MOUNTING CONDITIONS (RECOMMENDED)

- Perform mounting using the temperature profile shown below. To prevent thermal stress to the VCO, ensure gentle temperature gradients and use preheating whenever possible. (Recommended preheating: 140 °C to 160 °C for 60 s ± 20 s)
- Always consult FUJITSU MEDIA DEVICE beforehand if mounting more than once.
- Never remove a VCO that has already been mounted and attempt to reuse.
- For mounting, use a general-purpose flux suitable for mounting electronic components.



WASHING CONDITIONS

- Washing solution: Use isopropyl alcohol.
- Washing procedure: Immersion or steam cleaning is recommended.
- Washing time: For immersion: Less than 5 minutes at 40 °C or less.
 - For steam: Less than 2 minutes at 90 °C or less is recommended.

FUJITSU MEDIA DEVICES LIMITED

For further information please contact:

Japan

FUJITSU MEDIA DEVICE LIMITED International Sales & Marketing DEPT. Shin-Yokohama Square Bldg.,14F, Shin-yokohama 2-3-12, Kohoku-ku, Yokohama, Kanagawa 222-0033, Japan Tel: +81-45-471-0061 Fax: +81-45-471-0076

http://www.fujitsu.co.jp/hypertext/fmd/English/index.html

North and South America

FUJITSU MICROELECTRONICS, INC. 3545 North First Street, San Jose, CA 95134-1804, U.S.A. Tel: +1-408-922-9000 Fax: +1-408-922-9179

Customer Response Center *Mon. - Fri.: 7 am - 5 pm (PST)* Tel: +1-800-866-8608 Fax: +1-408-922-9179

http://www.fujitsumicro.com/

Europe

FUJITSU MICROELECTRONICS EUROPE GmbH Am Siebenstein 6-10, D-63303 Dreieich-Buchschlag, Germany Tel: +49-6103-690-0 Fax: +49-6103-690-122

http://www.fujitsu-fme.com/

Asia Pacific

FUJITSU MICROELECTRONICS ASIA PTE. LTD. #05-08, 151 Lorong Chuan, New Tech Park, Singapore 556741 Tel: +65-281-0770 Fax: +65-281-0220

http://www.fmap.com.sg/

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